

BAV100, BAV101, BAV102, BAV103

Vishay Semiconductors

Small Signal Switching Diodes, High Voltage



FEATURES

- Silicon epitaxial planar diode
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





APPLICATIONS

· General purposes

DESIGN SUPPORT TOOLS click logo to get started



MECHANICAL DATA

Case: MiniMELF (SOD-80)
Weight: approx. 31 mg
Cathode band color: black
Packaging codes / options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/2.5K per 7" reel (8 mm tape), 12.5K/box

PARTS TABLE						
PART	TYPE DIFFERENTIATION	ORDERING CODE	TYPE MARKING	CIRCUIT CONFIGURATION	REMARKS	
BAV100	V _{RRM} = 60 V	BAV100-GS18 or BAV100-GS08	-	Single	Tape and reel	
BAV101	V _{RRM} = 120 V	BAV101-GS18 or BAV101-GS08	-	Single	Tape and reel	
BAV102	V _{RRM} = 200 V	BAV102-GS18 or BAV102-GS08	-	Single	Tape and reel	
BAV103	V _{RRM} = 250 V	BAV103-GS18 or BAV103-GS08	-	Single	Tape and reel	

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT	
		BAV100	V_{RRM}	60	V	
Repetitive peak reverse voltage		BAV101	V_{RRM}	120	V	
Repetitive peak reverse voltage		BAV102	V_{RRM}	200	V	
		BAV103	V_{RRM}	250	V	
		BAV100	V_R	50	V	
Deverse veltere		BAV101	V_R	100	V	
Reverse voltage		BAV102	V _R	150	V	
		BAV103	V_R	200	V	
Peak forward surge current	t _p = 1 s		I _{FSM}	1	Α	
Repetitive peak forward current			I _{FRM}	625	mA	
Forward continuous current			I _F	250	mA	
Power dissipation			P _{tot}	500	mW	

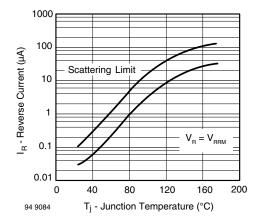


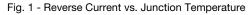
Vishay Semiconductors

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Thermal resistance junction to lead		R_{thJL}	350	K/W		
Thermal resistance junction to ambient air	On PC board 50 mm x 50 mm x 1.6 mm	R _{thJA}	500	K/W		
Junction temperature		Tj	175	°C		
Storage temperature range		T _{stg}	-65 to +175	°C		

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 100 mA		V _F			1	V
	V _R = 50 V	BAV100	I _R			100	nA
	V _R = 100 V	BAV101	I _R			100	nA
	V _R = 150 V	BAV102	I _R			100	nA
Develop accordant	V _R = 200 V	BAV103	I _R			100	nA
Reverse current	$T_j = 100 ^{\circ}\text{C}, V_R = 50 ^{\circ}\text{V}$	BAV100	I _R			15	μΑ
	T _j = 100 °C, V _R = 100 V	BAV101	I _R			15	μΑ
	T _j = 100 °C, V _R = 150 V	BAV102	I _R			15	μΑ
	T _j = 100 °C, V _R = 200 V	BAV103	I _R			15	μΑ
	$I_R = 100 \mu A, t_p/T = 0.01,$ $t_p = 0.3 \text{ ms}$	BAV100	V _(BR)	60			V
Breakdown voltage	$I_R = 100 \mu A, t_p/T = 0.01,$ $t_p = 0.3 \text{ ms}$	BAV101	V _(BR)	120			V
	$I_R = 100 \mu A, t_p/T = 0.01,$ $t_p = 0.3 \text{ ms}$	BAV102	V _(BR)	200			V
		BAV103	V _(BR)	250			V
Diode capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz,}$ $V_{HF} = 50 \text{ mV}$		C _D		1.5		pF
Differential forward current	I _F = 10 mA		r _f		5		Ω
Reverse recovery time	$I_F = I_R = 30 \text{ mA},$ $I_R = 3 \text{ mA}, R_L = 100 \Omega$		t _{rr}			50	ns

TYPICAL CHARACTERISTICS ($T_{amb} = 25$ °C, unless otherwise specified)





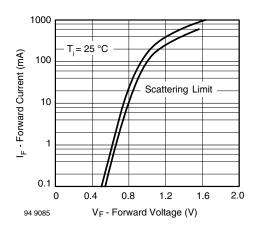


Fig. 2 - Forward Current vs. Forward Voltage

Vishay Semiconductors

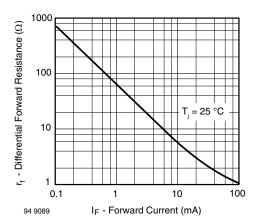
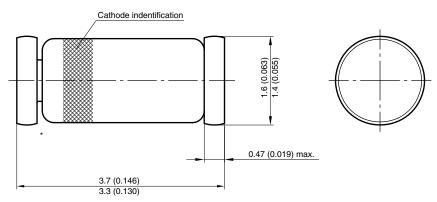
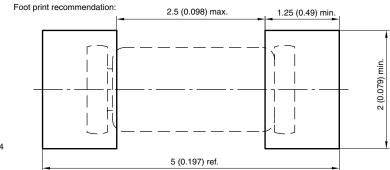


Fig. 3 - Differential Forward Resistance vs. Forward Current

PACKAGE DIMENSIONS in millimeters (inches): MiniMELF (SOD-80)



^{*} The gap between plug and glass can be either on cathode or anode side



Document no.:6.560-5005.01-4 Rev. 8 - Date: 07.June.2006 96 12070



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.